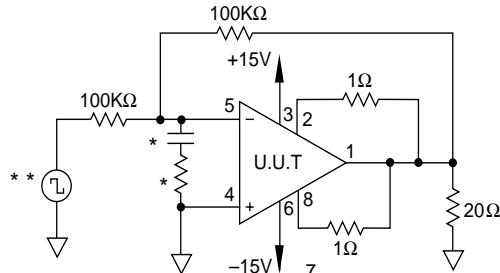


TABLE 4 GROUP A INSPECTION
PA51M

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SG	PARAMETER	SYMBOL	TEMP.	POWER	TEST CONDITIONS	MIN	MAX	UNITS
1	Quiescent current	I_Q	25°C	$\pm 34V$	$V_{IN} = 0, A_V = 100, R_{CL} = .1\Omega$		10	mA
1	Input offset voltage	V_{OS}	25°C	$\pm 34V$	$V_{IN} = 0, A_V = 100$		± 10	mV
1	Input offset voltage	V_{OS}	25°C	$\pm 10V$	$V_{IN} = 0, A_V = 100$		± 16	mV
1	Input offset voltage	V_{OS}	25°C	$\pm 40V$	$V_{IN} = 0, A_V = 100$		± 11.2	mV
1	Input bias current, +IN	$+I_B$	25°C	$\pm 34V$	$V_{IN} = 0$		± 40	nA
1	Input bias current, -IN	$-I_B$	25°C	$\pm 34V$	$V_{IN} = 0$		± 40	nA
1	Input offset current	I_{OS}	25°C	$\pm 34V$	$V_{IN} = 0$		± 10	nA
3	Quiescent current	I_Q	-55°C	$\pm 34V$	$V_{IN} = 0, A_V = 100, R_{CL} = .1\Omega$		10	mA
3	Input offset voltage	V_{OS}	-55°C	$\pm 34V$	$V_{IN} = 0, A_V = 100$		± 15.2	mV
3	Input offset voltage	V_{OS}	-55°C	$\pm 10V$	$V_{IN} = 0, A_V = 100$		± 21.2	mV
3	Input offset voltage	V_{OS}	-55°C	$\pm 40V$	$V_{IN} = 0, A_V = 100$		± 16.4	mV
3	Input bias current, +IN	$+I_B$	-55°C	$\pm 34V$	$V_{IN} = 0$		± 72	nA
3	Input bias current, -IN	$-I_B$	-55°C	$\pm 34V$	$V_{IN} = 0$		± 72	nA
3	Input offset current	I_{OS}	-55°C	$\pm 34V$	$V_{IN} = 0$		± 26	nA
2	Quiescent current	I_Q	125°C	$\pm 34V$	$V_{IN} = 0, A_V = 100, R_{CL} = .1\Omega$		13	mA
2	Input offset voltage	V_{OS}	125°C	$\pm 34V$	$V_{IN} = 0, A_V = 100$		± 16.5	mV
2	Input offset voltage	V_{OS}	125°C	$\pm 10V$	$V_{IN} = 0, A_V = 100$		± 22.5	mV
2	Input offset voltage	V_{OS}	125°C	$\pm 40V$	$V_{IN} = 0, A_V = 100$		± 17.7	mV
2	Input bias current, +IN	$+I_B$	125°C	$\pm 34V$	$V_{IN} = 0$		± 80	nA
2	Input bias current, -IN	$-I_B$	125°C	$\pm 34V$	$V_{IN} = 0$		± 80	nA
2	Input offset current	I_{OS}	125°C	$\pm 34V$	$V_{IN} = 0$		± 30	nA
4	Output voltage, $I_o = 10A$	V_o	25°C	$\pm 18V$	$R_L = 1\Omega$	10		V
4	Output voltage, $I_o = 68mA$	V_o	25°C	$\pm 40V$	$R_L = 500\Omega$	34		V
4	Output voltage, $I_o = 4A$	V_o	25°C	$\pm 30V$	$R_L = 6\Omega$	24		V
4	Current limits	I_{CL}	25°C	$\pm 16V$	$R_{CL} = 1\Omega, R_{CL} = .1\Omega$	5	7.9	A
4	Stability/noise	E_N	25°C	$\pm 34V$	$R_L = 500\Omega, A_V = +1, C_L = 1.5nF$		1	mV
4	Slew rate	SR	25°C	$\pm 34V$	$R_L = 500\Omega$	1.0	10	V/ μ s
4	Open loop gain	A_{OL}	25°C	$\pm 34V$	$R_L = 500\Omega, F = 10Hz$	94		dB
4	Common-mode rejection	CMR	25°C	$\pm 15V$	$R_L = 500\Omega, F = DC, V_{CM} = \pm 9V$	70		dB
6	Output voltage, $I_o = 10A$	V_o	-55°C	$\pm 18V$	$R_L = 1\Omega$	10		V
6	Output voltage, $I_o = 68mA$	V_o	-55°C	$\pm 40V$	$R_L = 500\Omega$	34		V
6	Output voltage, $I_o = 4A$	V_o	-55°C	$\pm 30V$	$R_L = 6\Omega$	24		V
6	Stability/noise	E_N	-55°C	$\pm 34V$	$R_L = 500\Omega, A_V = +1, C_L = 1.5nF$		1	mV
6	Slew rate	SR	-55°C	$\pm 34V$	$R_L = 500\Omega$	1.0	10	V/ μ s
6	Open loop gain	A_{OL}	-55°C	$\pm 34V$	$R_L = 500\Omega, F = 10Hz$	94		dB
6	Common-mode rejection	CMR	-55°C	$\pm 15V$	$R_L = 500\Omega, F = DC, V_{CM} = \pm 9V$	70		dB
5	Output voltage, $I_o = 8A$	V_o	125°C	$\pm 16V$	$R_L = 1\Omega$	8		V
5	Output voltage, $I_o = 68mA$	V_o	125°C	$\pm 40V$	$R_L = 500\Omega$	34		V
5	Output voltage, $I_o = 4A$	V_o	125°C	$\pm 30V$	$R_L = 6\Omega$	24		V
5	Stability/noise	E_N	125°C	$\pm 34V$	$R_L = 500\Omega, A_V = +1, C_L = 1.5nF$		1	mV
5	Slew rate	SR	125°C	$\pm 34V$	$R_L = 500\Omega$	1.0	10	V/ μ s
5	Open loop gain	A_{OL}	125°C	$\pm 34V$	$R_L = 500\Omega, F = 10Hz$	94		dB
5	Common-mode rejection	CMR	125°C	$\pm 15V$	$R_L = 500\Omega, F = DC, V_{CM} = \pm 9V$	70		dB

BURN IN CIRCUIT


* These components are used to stabilize device due to poor high frequency characteristics of burn in board.

** Input signals are calculated to result in internal power dissipation of approximately 2.1W at case temperature = 125°C.